



Product Overview

2N5655: High Voltage NPN Bipolar Power Transistor

For complete documentation, see the data sheet

Product Description

These devices are designed for use in line-operated equipment such as audio output amplifiers; low-current, high-voltage converters; and AC line relays.

Features

- Excellent DC Current Gain
 $h_{FE} = 30\text{-}250 @ I_C = 100 \text{ mAdc}$
- Current-Gain - Bandwith Product -
 $f_T = 10\text{MHz (Min) } @ I_C = 50 \text{ mAdc}$
- Pb-Free Packages are Available

Part Electrical Specifications

Product	Compliance	Status	Polarity	I_C Continuous (A)	$V_{(BR)CEO}$ Min (V)	h_{FE} Min	h_{FE} Max	f_T Min (MHz)	P_{TM} Max (W)	Package Type
2N5655G	Pb-free Halide free	Active	NPN	0.5	250	30	250	10	20	TO-225-3

For more information please contact your local sales support at www.onsemi.com

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